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Characterization of a Novel System of Bismuth Lead Borosilicate Glass Containing Copper

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Abstract

Objectives: The primary objective of the present investigation was to examine the impact of Bi^{3+} ions on the optical, radiation shielding, dielectric and structural characteristics of lead borosilicate glasses doped with CuO. **Method:** In this view, we planned to utilize the conventional rapid melt quenching method to produce glasses with the following chemical composition: 25 PbO + 15 B2O³ + 0.1 CuO + (59.9-x) SiO² :x Bi2O³ (0*≤*x*≤*12). **Findings:** The samples' non-crystalline characteristics were validated through XRD and SEM analysis, respectively, while their glass-forming capabilities were assessed through DTA studies. Utilizing the FT–IR and Raman analyses, the numerous structural units were determined. According to the findings of the FT-IR, and Raman analyses, the degree of disorder in the glass network increased. By means of optical absorption experiments, the optical properties of glasses were determined. The results obtained from optical absorption spectral investigations indicated that the concentration of octahedral Cu^{2+} ions increased gradually as the $Bi₂O₃$ concentration increased to 12 mol %. The dielectric properties of the glasses, suggested that the dielectric constant values of glasses containing $Bi₂O₃$ in concentrations below 12 mol% increase gradually. Additionally, the radiation shielding properties of the glasses are investigated. The values of radiation protection ability found to be purely function of $Bi₂O₃$ concentration. **Novelty:** The results suggest that the glasses' thermal stability, dielectric constant, optical band gap and radiation shielding ability values purely function of Bi₂O₃ concentration.

Keywords: Borosilicate glasses; Thermal stability; Optical absorption; Radiation shielding properties; Dielectricsq

1 Introduction

Similar to borotelluride or borophosphate glasses, multicomponent borosilicate glasses exhibit durability when subjected to similar circumstances. In general, the surface contamination resistance is the main feature of borosilicate glasses $^{(1)}$ $^{(1)}$ $^{(1)}$. A thin layer of

condensation forms from the water vapor on the borosilicate glass, which does not obstruct the clarity of light passing through the glass^{[\(2\)](#page-9-1)}. When compared to numerous other mixed glass former glasses, borosilicate glasses containing various metal cations have exceptionally extensive network forming units. Compared to ultra-silicate glasses of equivalent composition, those composed of borosilicate and lead and bismuth heavy metal ions exhibit considerably greater stability and durability $^{(3)}$ $^{(3)}$ $^{(3)}$. Lead borosilicate glass systems are among the most suitable for forming mixed glass networks due to their extremely nonlinear compositional dependencies on glass transition temperature and ionic conductivity. In addition to serving as electrolytes in solid electrochemical cells, lead borosilicate glasses are also utilized in vacuum energy storage safety devices $^{(4)}$ $^{(4)}$ $^{(4)}$. Recently, there has been a significant focus among researchers on the advancement of crystalline or amorphous solid electrolyte materials that exhibit exceptional electrical properties. As a result, glasses composed of lead borosilicate have been recognized as electrolyte materials with exceptional efficiency^{[\(5\)](#page-10-2)}. Under PbO's substantial band gap, glasses containing it exhibit exceptional transparency, even in the ultraviolet (UV) spectrum, thereby enhancing their resistance to moisture. By incorporating heavy metal oxides such as Bi_2O_3 into lead borosilicate glasses, one can impart them with distinct properties including elevated density, refractive index, dielectric constant, NIR transmission with favorable photothermal characteristics, and reduced phonon losses^{[\(6,](#page-10-3)[7\)](#page-10-4)}. The incorporation of various transition metal ions, including Cr, Cu, and Ti, significantly enhances the properties of lead borosilicate glasses. Glasses containing Cu^{2+} are viable candidates for Q-switching circuits and non-linear optical absorbers for assisting passive laser beam variations $^{(8)}$ $^{(8)}$ $^{(8)}$. Lead borophosphate glass systems doped with different transition metal oxides are one of the most suitable mixed glass network formers, which exhibit strong non-linear compositional dependence of space charge polarization and mass attenuation coefficient for various types of irradiations. Because of these reasons lead borosilicate glasses have significant applications such as electrolytes in solid electrochemical cells, vacuum, energy storage, radiation protection materials etc.^{[\(9\)](#page-10-6)}.

1.1 Research Gap

The cupper ions with the 3d⁹ configuration are primarily found in the divalent state Cu²⁺, where they can occupy a tetrahedral or octahedral occupancy depending on the glass's environment.The composition at normal temperature and pressure is the sole determinant of their capacity to modify or generate glass. It is hypothesized that the dual occupancy is because of the minor disparity in ligand field stabilization energy between the two potential coordination states of Cu^{2+} ions. These glasses may find use in the industrial sector as structural tracers in glasses, carbon monoxide sensors, and catalysts for the reduction of carbon monoxide $^{(10)}$ $^{(10)}$ $^{(10)}$. We have investigated the effects of copper ions on the structural, optical, and dielectric characteristics of Bi $_2\rm O_3$ doped lead borosilicate glasses in this study using characterization techniques as XRD, SEM, EDS, DTA, FT–IR, Raman, optical absorption, radiation shielding, and dielectric dispersion studies.

2 Methodology

For this investigation, the chemical composition of 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂:x Bi₂O₃ has been selected. Table [1](#page-1-0) contains the complete composition. The precise concentrations of the analytic grades of PbO, Bi_2O_3 , Boric acid (H₃BO₃), $SiO₂$, and CuO chemicals (all expressed in mole percent) were carefully mixed in an agate mortar and then liquefied in a densely walled crucible in an automatic temperature furnace for about 30 minutes, or until a transparent liquid without of voids created.

The final mixture was poured into a brass mold around at 1345 to 1350 *◦*C, which was subsequently annealed gradually at 250 *◦*C in a muffle furnace. Utilizing a Scale Tech digital weighing balance, the mass of the prepared containers was measured with a precision of 10-4 grams. The O-xylene liquid and the Archimedes method were employed to determine the densities (*[±]* 0.0001 g/cm³) of the glass samples that were produced. After reducing the samples to the specified dimensions of 1x 1 x 0.2 cm³, they were appropriately polished. To validate the non-crystalline characteristics of the fabricated glasses, X-ray diffraction traces were captured utilizing a PAN analytical instrument equipped with X'Pert³ Powder. Sample surface morphology as captured by the Hitachi S-3700N Spectrometer. The DTG – 60H (SHIMADZU) was utilized to conduct differential thermal analysis on the prepared samples.The instrument operated at a heating rate of 5.0 *◦*C per minute, covering a temperature range of 27 to 1400 *◦*C. The produced glasses were subjected to optical absorption investigations at room temperature using an Agilent Technologies Carry 5000 UV to NIR Region instrument with a 0.1 nm resolution within the 200 – 2200 nm wavelength range. The spectral measurements in the FT-IR range of $400-4000 \text{ cm}^{-1}$ were acquired using a Perkin Elmer Spectrum Two instrument with four scans. Raman spectral measurements were acquired utilizing a Horrible Jobin Yvon Germany, LASER (633 nm), 20-2000 nm instrument, 100x objective lens. Utilizing Phy-x and PSD software to obtain radiation shielding measurements. The Auto lab Impudence analyzer was utilized to conduct dielectric measurements across a frequency range of 1 kHz to 1 MHz.

3 Results and Discussion

The photograph of the prepared 25 PbO + [1](#page-2-0)5 B_2O_3 + 0.1 CuO + (59.9-x) SiO₂ :x Bi₂O₃ glasses is in a shown Figure 1(a). The test glasses' X-ray diffraction patterns are reported in Figure [1](#page-2-0)**(b)**, which reveal no crystalline peaks in the X-ray diffraction results $^{(11)}$ $^{(11)}$ $^{(11)}$. With respect to XRD intensities, the CuBi-12 glass was noticed highest in diffraction intensities. As per earlier research, the maximum diffraction intensities of test samples might be attributed to the closest structural compactness, least distance between atoms, highest density, and least molar volume. The chemical composition of the CuBi-12 glass verified using energy dispersion spectra. Which signifies the chemicals such as oxygen, bismuth, lead, copper boron and silicon with in the glass. Which also reveal 25 mol% of PbO, 15 mol% of B_2O_3 , 0.1 mol% of CuO, 47.9 mol% of SiO₂ and 12 mol% of Bi_2O_3 with atomic weight % of glass. All these results of the CuBi-12 glass chemical analysis represented in Figure [1](#page-2-0) **(c)**. The surface morphology of the 25 PbO + 15 B_2O_3 + 0.1 CuO + (59.9-x) SiO₂ :x Bi₂O₃test samples recorded, which are observed to have no crystalline behavior. At 10, 20, 5 0 and 100 mm range, one of the tests CuBi-12 glass morphological reports of test glasses represented in Figure [2](#page-3-0) which is suggesting glassy behavior.

Fig 1. (a) The photograph, (b) XRD patterns, and (c) Chemical analysis of the CuBi-12 glass of 25 PbO + 15 B2**O**3 **+ 0.1 CuO + (59.9-x) SiO**2 **: x Bi**2**O**3 **glasses**

The physical properties of 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂ :x Bi₂O₃glasses reported in Table [2.](#page-3-1) For the prepared glasses, as the concentration of Bi_2O_3 increases, the density depends and an increase in average molecular weight is observed. As the concentration of CuO increases, the anticipated ionic concentration, field strength, and molar volume increase. Whereas the associated ionic radius and polaron radius decrease (12) (12)

It was discovered that the glass transition temperature of the 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂ :x Bi₂O₃ glasses was 420 °C, and that the value of T_g increased as the concentration of Bi₂O₃ increased. The value of the exothermic peak, which is seen at the glass crystallization temperature (T_c) of roughly 850 °C, rises with the concentration of Bi2O3 $^{(13)}$ $^{(13)}$ $^{(13)}$. The thermal stability { $(Tc-T_g)/T_g$ } of glass was assessed using T_g and T_c of the glasses sample.

The usual vibrational bands of borate groups, silicate groups, PbO, Bi₂O₃, and CuO structural units are displayed in the FT-IR spectra of 25 PbO + 15 B₂O₃ + 0.1 CuO+ (59.9-x) SiO₂: x Bi₂O₃ glasses, as provided in Table [4](#page-4-0) and illustrated in Figure 4. SiO₂ vibrational modes, including symmetrical and asymmetrical Si-O-Si units, are observed at around 926–937 cm⁻¹ and 762–771 cm⁻¹. Regions of 1394–1406 cm⁻¹, 926–937 cm⁻¹, and 692–709 cm⁻¹, respectively, are the bands that originate from BO₃, BO₄

Fig 2. Surface morphology of the CuBi-12 glass at 10, 20, 50 and 100 mm range

Table 3. Summary on data of DTA studies of 25 PbO + 15 B2O3 **+ 0.1 CuO + (59.9-x) SiO**2 **:x Bi**2**O**3 **glasses**

units, and B-O-B connections. The Pb-O-Pb symmetric units were observed at 692 - 709 cm⁻¹ in the vicinity, respectively. In the ranges, $606 - 612$ cm⁻¹ and $434 - 446$ cm⁻¹, respectively, the BiO₄ tetrahedral and BiO₆ octahedral vibrations were observed. Within the range of 694–709 cm^{-1} , the bands resulting from Cu–O specific vibrations will be predicted $^{(14,15)}$ $^{(14,15)}$ $^{(14,15)}$ $^{(14,15)}$.

As seen in Figure [5,](#page-4-1) the Raman spectra of the 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂ : x Bi₂O₃ glasses exhibit characteristic vibrational bands of PbO, Bi_2O_3 , CuO, silicate groups, and borate groups. Table [5](#page-5-0) contained the Raman band assignment. The SiO₂ vibrational modes observed at 784 – 799 cm⁻¹ and 1052 – 1067 cm⁻¹ include Si-O-Si bending and stretching units.

Fig 3. DTA thermograms of the 25 PbO + 15 B2**O**3 **+ 0.1 CuO + (59.9-x) SiO**2 **:x Bi**2**O**3 **glasses**

Fig 4. FT-IR spectra of 25 PbO + 15 B2**O**3 **+ 0.1 CuO + (59.9-x) SiO**2 **:x Bi**2**O**3 **glasses recorded at room temperature**

Fig 5. Raman spectra of 25 PbO + 15 B2O3 **+ 0.1 CuO + (59.9-x) SiO**2 **:x Bi**2**O**3 **glasses recorded at room temperature**

The regions 794 –776 cm⁻¹, 741 – 757 cm⁻¹ and 692 – 709 cm⁻¹ are home to the bands that originate from BO₃, BO4 units, and B-O-B connections, respectively. The Pb–O–Pb symmetric units were observed at 667 and 690 cm–1 in the vicinity, respectively. The areas 606 – 612 cm⁻¹ and 395 – 415 cm⁻¹ are where the BiO₄ tetrahedral and BiO₆ octahedral vibrations were seen, respectively. In the range of 632 – 645 cm⁻¹, the bands resulting from Cu–O specific vibrations are anticipated $^{(16,17)}.$ $^{(16,17)}.$ $^{(16,17)}.$ $^{(16,17)}.$ $^{(16,17)}.$

The optical absorption spectrum of 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂ :x Bi₂O₃ glasses, recorded at room temperature, is shown in Figure [6](#page-5-1)**(a)**. The band gap values of glasses can be found by examining the Tauc plots of glasses, as shown in Figure [6](#page-5-1) **(b)**. In this view, the glass with the highest concentration of CuO 12 mol% among all the other glasses was noted. Table [6](#page-5-2) presents the results of current glasses together with identifications and evaluations of the absorption spectra $^{(18)}$ $^{(18)}$ $^{(18)}$. As the amount of Bi_2O_3 increases, the optical band gap parameter decreases, as shown by the Tauc plots and observed optical absorption spectra of the current glasses. This is because there are more non-bridging oxygens and bond defects in the glass ceramic network, which in turn lead to Cu²⁺ and Bi³⁺ ions depolymerizing the network of glass ceramics. When Bi₂O₃ is added to the glass network up to a 12 mol% concentration, $CuO₆$ ions rise and various donor ions develop, which tend to overlap with excited states of electrons. These many explanations show that the impurity energy band diffuses into the original band gap, causing the optical band gap to decrease (19) (19) .

Fig 6. (a) Optical absorption spectra of 25 PbO + 15 B2O3 **+ 0.1 CuO + (59.9-x) SiO**2 **:x Bi**2**O**3 **glasses recorded at room temperature, (b) Tauc plots of 25PbO+ 15 B**2**O**3 **+ 0.1 CuO + (59.9-x) SiO**2 **: x Bi**2**O**3 **glasses**

Table 6. Summary on optical absorption of 25 PbO + 15 B2O3 **+ 0.1 CuO + (59.9-x) SiO**2 **:x Bi**2**O**3 **glass materials recorded at room**

temperature								
Glass	CuBi-0	CuBi-3	CuBi-5	CuBi-8	CuBi-10	$CuBi-12$		
Optical band gap (eV)	3.3	3.2		2.5		1.5		
Urbach Energy (eV)	0.0785	0.0781	0.0776	0.0771	0.0766	0.0762		

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The optical absorption spectra of the 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂ :x Bi₂O₃ glasses indicate that Cu²⁺ ions deform and occupy octahedral sites at low concentrations of $Bi₂O₃$. As the concentration increases up to 12 mol%, the occupancy rate increases; however, as the concentration increases, the octahedral occupancy in the glass matrix decreases. An increase of 12 mol% of Bi_2O_3 in the concentration of Bi^{3+} ions at octahedral sites in the glass system results in a greater production of NBOs and bound electrons at donor centers. Consequently, vacant third states of adjacent Cu^{2+} ion sites coincide with the excited states of the localized electrons that were initially confined in Cu⁺ sites. Consequently, the absorption edge transitions to the higher wavelength region, and the optical band gap diminishes substantially due to the widening and merging of the impurity band with the main band.The observed alterations in the absorption edge and optical band gap may be attributed to a reduction in the interaction between the p-electrons in the conductions band of silicate ions and the localized d electrons of substitutionally positioned copper ions. As network modifiers, the octahedral copper ions consequently decrease the rigidity of the produced samples. An increase in the concentration of Bi_2O_3 (> 12 mol%) in the glasses results in a reduction in the density of interrelated groups containing ions positioned interstitial and the concentration of NBOs. This phenomenon potentially signifies a decline in the number of donor centers occupied by electrons. The absorption edge inherently shifts in favor of shorter wavelengths due to the expansion of the optical band gap.

Using the Phy-X/PSD programme the shielding characteristics of the 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂ :x Bi2O3 glasses are examined. The half value layer characterizes how well the radiation can pass through the test glasses. Additionally, it helps with shielding design. The sample's mean free path indicates how well photons can pass through it. It is discovered that there is an increase in photon energy variation in the values of MAC $^{(20)}$ $^{(20)}$ $^{(20)}$. The results indicate that the Cu²⁺ ions are indicated by the K-absorption edge at approximately 0.0679 MeV.The fluctuation in MAC, MFP (mean free path), HVL (half layer width), and RPE (radiation protection efficiency) with increasing incident photon energy is reported in Figure [7](#page-6-0)**(a), (b), (c),** and **(d)**. Test glasses have a higher degree of density due to the CuO⁶ octahedral units. The structural units of Pb-O-Si, Bi-O-B, and Bi-O-Cu are the additional cause of the high glass density. It is possible to represent the MAC tendency versus photon energy using an exponential decaying pattern.

Fig 7. (a) Variation in MAC, (b) Variation in MFP, (c) Variation in HVL, and (d) Variation in RPE with Photon energy of 25 PbO + 15 B2**O**3 **+ 0.1 CuO + (59.9-x) SiO**2 **: x Bi**2**O**3 **glasses**

Additionally, as the content of $Bi₂O₃$ in the glass samples increased, the MAC values were also shown to increase. For the glasses recorded as CuBi-0 to CuBi-12, the MAC values at low energy photons $E = 0.015$ MeV are 17.181 and 17.371, respectively. Based on the amount of $Bi₂O₃$ contained in the glasses, the minimal variation in the MAC values of the test glass can be understood. The other two molecular components of the glass system, such as $Bi₂O₃$, PbO and $B₂O₃$, are maintained at an equimolar fraction in each of the manufactured glasses. The mol% of Bi_2O_3 in these glasses is increased from 0.0 to 12 mol% compared to the $Bi₂O₃$ concentration.

room temperature									
Glass	$CuBi-0$	$CuBi-3$	CuBi-5	$CuBi-8$	$CuBi-10$	$CuBi-12$			
MAC (at 0.02 MeV)	15.245	18.245	21.225	32.345	34.545	41.045			
MFP (at 10 MeV)	32	27	19	14.1	10.2	7.5			
HVL (at 10 MeV)	14.22	13.75	12.85	12.62	11.45	10.21			
RPE(%)	30.5	28.5	27	26	24	22			

Table 7. Summary on radiation shielding properties of 25PbO + 15 B_2O_3 **+ 0.1 CuO + (59.9-x) SiO₂ : x** Bi_2O_3 **glasses recorded at**

Another cause of the change in MAC values with rising Bi^{3+} ions is the NBOs during glass formation. Since the Pb²⁺, Bi^{3+} , $Si⁴⁺$ and $Cu²⁺$ ions in the glasses have site symmetry, there is a greater increase in MAC values in low photon energy range. For glasses CuBi-0.0 to CuBi-2.5, LAC has values of 0.17 to 0.2 cm-1 at an energy of 1 MeV, respectively. Because it has the largest atomic number and ρ , glass CuBi-12 has the highest LAC values $^{(21)}$ $^{(21)}$ $^{(21)}$. The figure also demonstrates how the LAC varies linearly with $Bi₂O₃$ concentration at these chosen energies. This could also be explained by the fact that the glass combinations contain a range of metals (like Bi2O3) and non-metals (like PbO, B2O3*,* SiO2 and CuO), as mentioned earlier. In the same perspective, as the amount of Bi³⁺ ions in the test glasses increases, so do the other dependent metrics including MFP, HVL, and RPE. CuBi-12 glass was seen to have good values for MAC, MFP, HVL, and RPE; CuBi-0, CuBi-3, CuBi-5, CuBi-8, and CuBi-12 glasses will also be beneficial as shielding glasses $^{(22)}$ $^{(22)}$ $^{(22)}$. Overall, the concentration of Bi $_2\rm O_3$ and the thickness of the glasses are the only factors that affect the radiation protection efficiency and shielding phenomena of the test glasses.

Fig 8.The variation in dielectric constant of 25 PbO + 15 B2**O**3 **+ 0.1 CuO + (59.9-x) SiO**2 **:x Bi**2**O**3 **glasses with temperature. Inset shows the variation of dielectric constant of glass Cu Bi-12 with temperature at different frequencies**

At 1 kHz, 10 kHz, and 100 kHz frequencies, as well as in the temperature range of 30 *◦*C to 250 *◦*C, the dielectric properties of the 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂ :x Bi₂O₃ glasses are measured. Wherein the temperature area of relaxation, activation energy conduction, ac conductivity, dielectric constant, and dielectric loss have all been assessed. The CuBi-12 glass was found to yield the best results. The change in dielectric constant with temperature is shown in Figure [8.](#page-7-0) The inset of the same image illustrates how the dielectric constant of CuBi-12 glass varies for frequency ranges of 1 kHz, 10 kHz, and 100 kHz. Figure [9](#page-8-0) illustrates how di-electric loss changes with temperature. The variation in the dielectric loss of the CuBi-12 glass at 1 kHz, 10 kHz, and 100 kHz frequency ranges is reported in the inset of the same figure. Figure [10](#page-8-1) illustrates how AC conductivity changes in response to an inverse temperature variation. The change in A.E. with increasing concentration of $Bi₂O₃$ is reported in the inset of the same figure. The dielectric constant, dielectric loss, ac conductivity, temperature zone of relaxation, and activation energy conduction with temperature and frequency all vary as the concentration of $Bi₂O₃$ grows due to differences in space charge polarization. polarization, which causes the variations in the values of dielectric constant, dielectric loss, ac conductivity, temperature region of relaxation, and activation energy conduction with temperature and frequency.

Some of the charge carriers in the glass network that travel across short atomic distances at lower frequencies trap the charge carriers inside the material's borders, resulting in space charge polarization. Due to this movement, the local field gets distorted, which increases the capacitance and eventually the dielectric constant $^{(23)}$ $^{(23)}$ $^{(23)}$. At concentrations up to 12 mol%, Bi2O3 improves the space charge polarization, dielectric constant, loss tangent, and AC conductivity of the host glasses. Furthermore, a trend

Fig 9. The variation of dielectric loss of 25 PbO + 15 B2**O**3 **+ 0.1 CuO + (59.9-x) SiO**2 **:x Bi**2**O**3 **glasses with temperature. Inset shows the variation of dielectric loss with temperature at different frequencies of glass CuBi-12**

of reversal in the Bi_2O_3 concentration is noted at 12 mol%. The relaxation time change exhibits compositional dependence as the concentration of $Bi₂O₃$ increases. The cross-linking of $Bi³⁺$ tetrahedral ions reduces as the concentration of $Bi₂O₃$ in the host glass exceeds 12 mol%. This reduces the generation of polaron-lattice ion couples, improving the dielectric constant, loss tangent, and ac conductivity for dipoles. From the same perspective, the glasses' activation energy increases over 12 mol% of the Bi₂O₃ concentration. At a specific frequency, space charge polarization is one of several polarization mechanisms in materials that causes the dielectric constant and AC conductivity to increase with temperature.

Fig 10. Variation of AC Conductivity of 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂ :x Bi₂O₃ glasses with 1/T. Inset shows the variation of activation energy with concentration of Bi2**O** 3

Changing ions (octahedrally positioned copper and borate ions mixed with Pb^{2+} ions) will cause bonding problems in the glass network. As a result, charge carriers can migrate more easily through these imperfections, which initiates space

charge polarization. The dielectric parameters and activation energy exhibit a positive correlation with progressive growth in concentration until reaching 12 mol% at any frequency and temperature. This suggests that the expanding quantities of octahedral Cu^{2+} ions functioning as modifiers contribute to an elevation in space charge polarization. An increase in the concentration of Bi₂O₃ beyond 12 mol% leads to an expansion of tetrahedral Cu²⁺ ions via glass forming connections with other elements of the tetrahedral glass network.This expansion ultimately results in a reduction in the space charge polarization. At lower frequencies, the QMT model deduces that the AC conductivity is determined by the density states of defects at the Fermi level $N(E_f)$. An increase in the quantity of CuO (up to 12 mol%) is observed to cause an increase in AC conductivity. This suggests that there are more free charge carriers available for conduction in the glass network or localized defect energy levels. However, above 12 mol% CuO, a reversal in conductivity is observed. As modifications, Cu^{2+} ions entering octahedral positions in the glass network will increase by up to 12 mol% of CuO the concentration of dangling bonds formed by lead ions and Cu²⁺ ions with different cations in the current glass samples $^{(24)}$ $^{(24)}$ $^{(24)}$. The atomic radius of Cu²⁺ ions, tri-valent oxidation state of Cu²⁺ ions, density of the glasses, intermolecular force between the Cu²⁺ ions to Bi³⁺, Pb²⁺, Si⁴⁺and B³⁺ ions, number of nonbridging oxygen's with in the glasses, and octahedral tendency of Cu^{2+} ions with in the glasses, is the main reason for enhanced properties of the structural, optical, radiation shielding and dielectric properties of present glasses. The specific results such as thermal stability (0.702), optical band gap (1.5 eV), radiation protection ability (\sim 22%) and dielectric constant (\sim 8.21) of present glasses are noticed to be great and comparable with previous literature (cited reference 13, 19, 21 and 23) are suggestable as thermally stable, optically active, radiation shielding dielectric glass resource.

4 Conclusion

The following conclusions are derived from the findings of the radiation shielding, optical, structural, and dielectric examinations of 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂ : x Bi₂O₃ glasses: Studies on glasses using XRD and SEM show glassy behavior. The chemical composition with atomic weight percentage is indicated by the EDX analysis. Physical parameters including density (~ 5.37 gm/cm³) and molar volume (~ 30.46 cm³ mol⁻¹) were determined to be optimal for the CuBi-12 glass. Similarly, the CrBi-12 glass was discovered to have the greatest values of GTT (about 594 *◦*C) and thermal stabilities (about 0.702) evolutions in the DTA examinations of glasses. The evaluation of structural alterations in the glass network brought about by compositional variations is provided by the FT-IR and Raman investigations. Due to an increase in the modifying activity of octahedral $Bi³⁺$ ions, these spectral investigations showed a rising degree of disorder with a rise in Bi₂O₃ concentration in glass series up to 12 mol%. At very low levels of concentration, the optical band gap (1.5 eV) values are also solely dependent on the concentration of $Bi₂O₃$, according to the optical absorption experiments. Up to 12 mol% of the $Bi₂O₃$ concentration, the majority of the Cu²⁺ ions are arranged in octahedral orientations. Radiation shielding characteristics such as MAC (~41.04 cm 2 /g) and RPE ($\sim22\%$) show that the shielding behavior is solely dependent on Bi $^{3+}$ ions. The range of the glasses' dielectric constant (~8.21), dielectric loss (~0.025), ac conductivity (~7.45 x 10⁻⁸ ohm⁻¹ cm⁻¹) and A.E. (~1.102 eV) values are revealed by their dielectric characteristics. These findings further demonstrate that the glasses' dielectric behavior is solely dependent on the presence of Bi^{3+} ions. Overall, the created 25 PbO + 15 B₂O₃ + 0.1 CuO + (59.9-x) SiO₂ :x Bi₂O₃ glasses are useful resources that are dielectric, mechanically hard, and effectively shield radiation.

5 Author's contribution statement

Mr. Madabushanam Gopi Krishna: Methodology, characterization, results, report drafting.

- Dr. Ravi Kumar Guntu: Methodology, analysis, and report correction.
- Dr. Md Shareefuddin: suggestions and report corrections.
- Dr. NV Prasad: Supervision, suggestions, and report corrections.

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